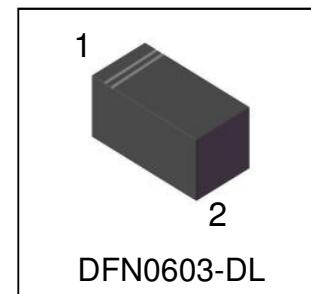


LNZ11F7V5T5G

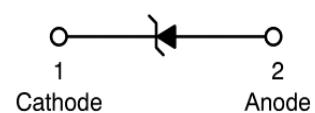
S-LNZ11F7V5T5G

SURFACE MOUNT ZENER DIODE



1. FEATURES

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.
- Small Surface Mount Package (0.61 x 0.31mm)
- Ultra-Low Profile Package (0.28mm)
- Steady State Power Rating of 250 mW
- Low Leakage Current
- Ideally Suited for Automated Assembly Processes



2. DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LNZ11F7V5T5G	a	15000/Tape&Reel

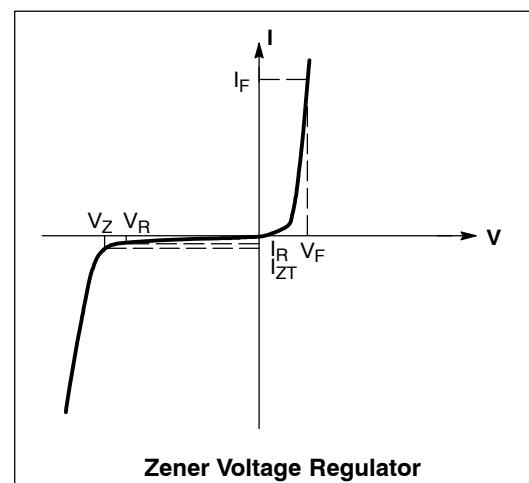
3. MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Total Power Dissipation on FR-5 Board(Note 1) @ $T_A = 25^\circ\text{C}$	PD	250	mW
Thermal Resistance, Junction to Ambient(Note 1)	R _{θJA}	500	°C/W
Junction and Storage Temperature Range	T _{J,Tstg}	-55~+150	°C

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

4. ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

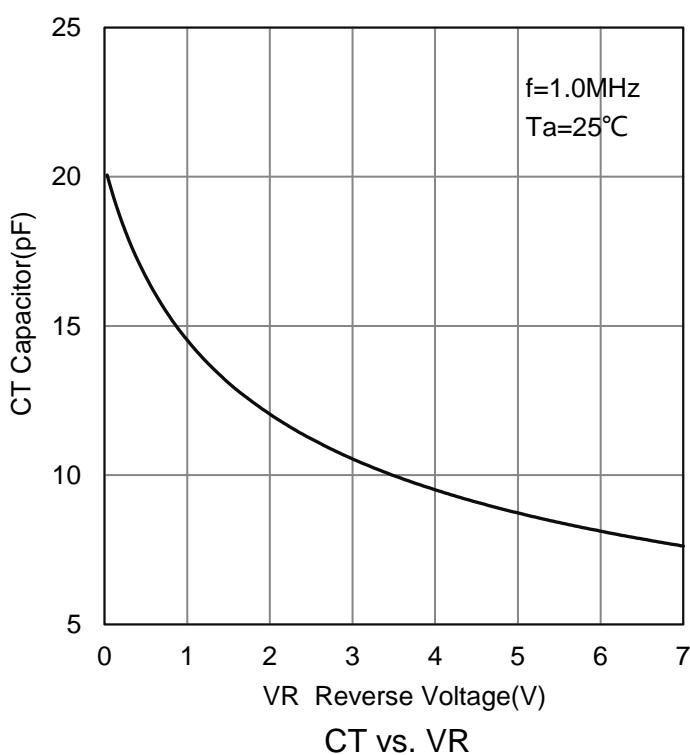
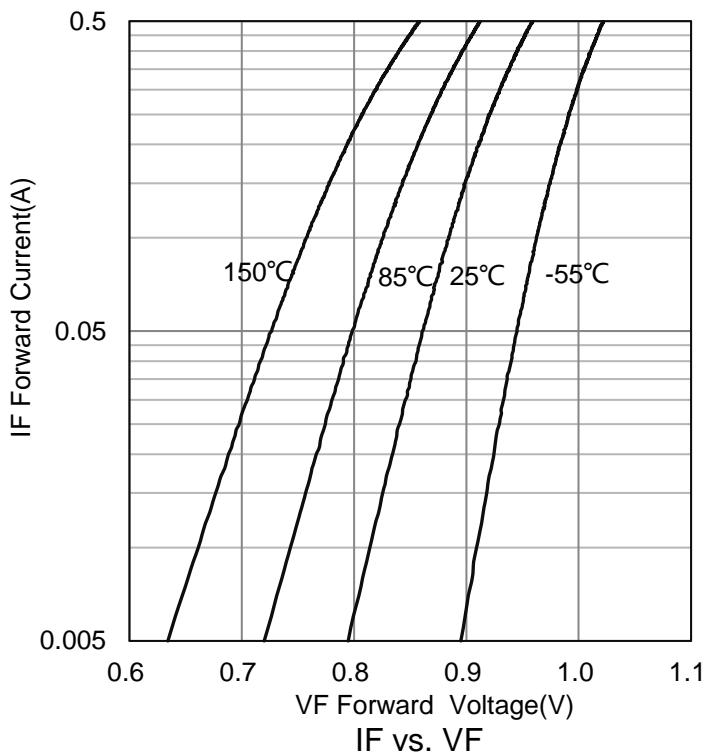
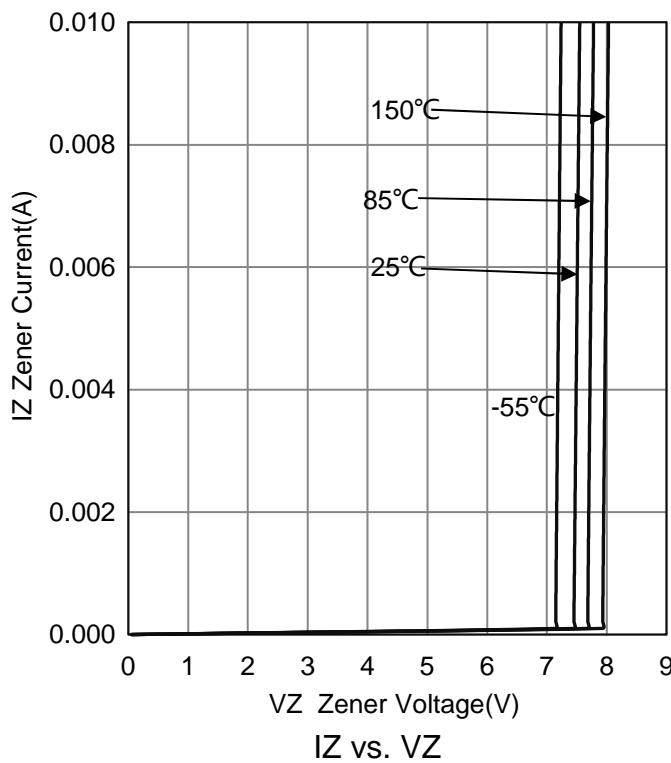
Symbol	Parameter
V _Z	Reverse Zener Voltage @ I _{ZT}
I _{ZT}	Reverse Current
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}
I _{ZK}	Reverse Current
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}
I _R	Reverse Leakage Current @ V _R
V _R	Reverse Voltage
I _F	Forward Current
V _F	Forward Voltage @ I _F
θ _{VZ}	Maximum Temperature Coefficient of V _Z
C	Max. Capacitance @ V _R = 0 and f = 1 MHz



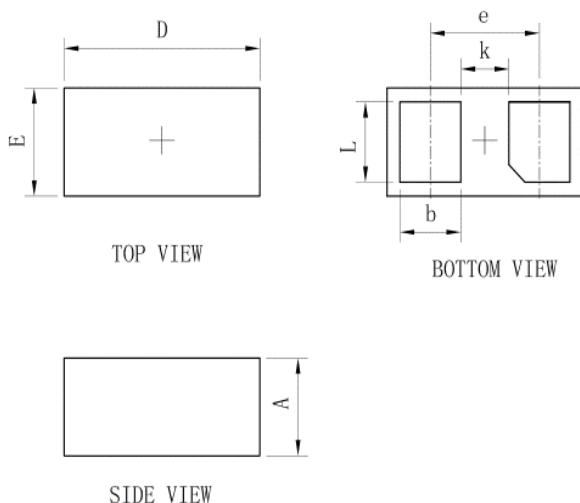
5. ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Zener Voltage (IZT=5mA)	VZ	7.11	-	7.9	V
Reverse Leakage Current (VR=5V)	IR	-	-	1	µA

6.ELECTRICAL CHARACTERISTICS CURVES



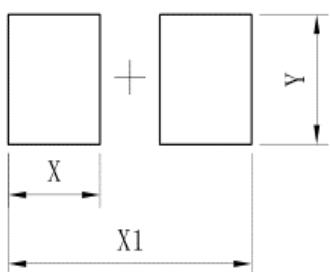
7. OUTLINE AND DIMENSIONS



DFN0603-DL			
Dim	Min	Typ.	Max
D	0.58	0.61	0.64
E	0.28	0.31	0.34
e	-	0.34	-
L	0.20	0.23	0.26
b	0.16	0.19	0.22
A	0.25	0.28	0.31
k	0.12	0.15	0.18

All Dimensions in mm

8. SOLDERING FOOTPRINT



DFN0603-DL	
DIM	(mm)
X	0.23
X1	0.61
Y	0.30